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SURFACE MOUNT LIGHT EMITTING CHIP PACKAGE

This application claims the benefit of U.S. provisional application serial no. 60/527,969 filed on December 9, 2003.

BACKGROUND

The following relates to the lighting arts. It is especially relates to
5 surface-mounted light emitting diodes for indicator lights, illumination applications, and the like, and will be described with particular reference thereto. However, the following will also find application in other areas that advantageously can employ surface-mountable light emitting devices.

Surface mounted light emitting packages typically employ a light
10 emitting chip such as a light emitting diode chip, a vertical cavity surface emitting laser, or the like. In some arrangements the chip is bonded to a thermally conductive sub-mount which is in turn bonded to a lead frame. The sub-mount provides various benefits such as improving manufacturability of electrical interconnections, improving thermal contact and conduction, and the
15 like. The lead frame is adapted to be surface mounted by soldering to a printed circuit board or other support.

Such arrangements have certain disadvantages. The thermal transfer path includes two intervening elements, namely the sub-mount and the lead frame. Moreover, electrical connections to the lead frame typically involve wire
20 bonds, which can be fragile. The mechanical connection between the sub-mount and the lead frame is typically effected in part by an epoxy or other type of encapsulating overmolding material. Such materials can have relatively high coefficients of thermal expansion which can stress wire bonds or mechanical connections.

The present invention contemplates an improved apparatus and method that overcomes the above-mentioned limitations and others.

BRIEF SUMMARY

According to one aspect, a light emitting package is disclosed. A chip carrier includes top and bottom principal surfaces. At least one light emitting chip is attached to the top principal surface of the chip carrier. A lead frame attached to the top principal surface of the chip carrier.

According to another aspect, a light emitter is disclosed. A chip carrier has top and bottom principal surfaces. At least one light emitting chip is attached to the top principal surface of the chip carrier. A lead frame electrically contacts electrodes of the at least one light emitting chip. A support including printed circuitry is provided. The lead frame electrically contacts the printed circuitry. The chip carrier is secured to the support without the lead frame intervening therebetween.

According to yet another aspect, a light emitting package comprises a chip carrier and a light emitting chip attached to the chip carrier.

According to still yet another aspect, a light emitting package comprises a light emitting chip and a lead frame electrically connected to electrodes of the light emitting chip.

Numerous advantages and benefits of the present invention will become apparent to those of ordinary skill in the art upon reading and understanding the present specification.

BRIEF DESCRIPTION OF THE DRAWINGS

The invention may take form in various components and arrangements of components, and in various process operations and arrangements of process operations. The drawings are only for purposes of illustrating preferred embodiments and are not to be construed as limiting the invention. The drawings of the light emitting packages are not to scale.

FIGURE 1 shows a side view of a light emitting package surface mounted to a printed circuit board.

FIGURES 2A and 2B show top and side views of another light emitting package.

5 FIGURE 3 shows a top view of yet another light emitting package.

FIGURES 4A, 4B, and 4C show, respectively, a top view of a chip carrier with four light emitting chips flip-chip bonded thereto, a top view of a lead frame, and a side view of a light emitting package constructed from the components of FIGURES 4A and 4B.

10 FIGURES 5A, 5B, and 5C show, respectively, a top view of a chip carrier with four light emitting chips bonded thereto with a front-side electrode of each chip wire bonded to the chip carrier, a top view of a lead frame, and a side view of a light emitting package constructed from the components of FIGURES 5A and 5B.

15 DETAILED DESCRIPTION OF PREFERRED EMBODIMENTS

With reference to FIGURE 1, a surface-mounted light emitting package **10** includes a light emitting chip **12**, such as a light emitting diode, a resonant cavity light emitting diode, a vertical cavity surface emitting laser, or the like, bonded to an electrically insulating chip carrier **14**. In FIGURE 1, a flip-chip bonding configuration is shown in which front-side electrodes of the light emitting chip **12** are bonded to electrically conductive layers **20, 22** disposed on a top principal surface **26** of the chip carrier **14**. An insulating gap **28** which may be an air gap or may be filled with an electrically insulating material such as an epoxy or other dielectric. The electrically conductive layers **20, 22** define first and second terminals of opposite electrical polarity. Flip-chip electrode bonds **32, 34** can be thermosonic bonds, conductive epoxy bonds, solder bonds, or the like.

The chip carrier **14** is preferably substantially thermally conductive. At least the top principal surface **26** of the chip carrier **14** is substantially electrically insulating. The chip carrier **14** can be made of an electrically insulating material such as semi-insulating silicon, a ceramic, or a thermally

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conductive but electrically insulating plastic. Alternatively, the chip carrier **14** can be made of an electrically conductive material with an insulating layer or coating applied at least to the top principal surface **26**. For example, the chip carrier **14** can be made of conductive silicon with a silicon dioxide layer disposed on the top principal surface **26**, or the chip carrier **14** can be made of a metal with an insulator disposed on the top principal surface **26**, or so forth.

The electrically conductive layers **20**, **22** extend away from the die attach region where the light emitting chip **12** is flip chip bonded. Lead frame elements **40**, **42**, which are electrically conductive and electrically isolated from one another, are secured to and electrically contact portions of the electrically conductive layers **20**, **22** distal from the die attach region. The lead frame **40**, **42** is attached to the top principal surface **26** of the chip carrier **14**. The lead frame element **40** includes an electrical lead **46** distal from the chip carrier **14** and a bend **48** such that the lead **46** is approximately coplanar with a bottom principal surface **50** of the chip carrier **14**. Similarly, the lead frame element **42** includes an electrical lead **52** distal from the chip carrier **14** and a bend **54** such that the lead **52** is approximately coplanar with the bottom principal surface **50** of the chip carrier **14**. Electrical and physical bonding of the lead frame elements **40**, **42** to the top principal surface **26** of the chip carrier **14** is suitably achieved by solder bonds **54**, **56**. The lead frame **40**, **42** is suitably made of copper or another highly conductive material.

An overmolding or encapsulant **60** is disposed over the light emitting chip **12** and the top principal surface **26** of the chip carrier **14**, and also encapsulates a portion of the lead frame elements **40**, **42** proximate to the chip carrier **14**. The leads **46**, **52** of the lead frame **40**, **42** as well as the bottom principal surface **50** of the chip carrier **14** extend outside of the encapsulant **60**. Optionally, a wavelength-converting phosphor layer **62** coats the encapsulant **60** and fluorescently or phosphorescently converts light emitted by the light emitting chip **12** to another wavelength or range or plurality of wavelengths.

The chip carrier **14** and the light emitting chip **12** and lead frame **40**, **42** bonded to the top principal surface **26** of the chip carrier **14**, together with the optional encapsulant **60** and phosphor layer **62**, collectively define a surface

mountable unit that is surface-mounted on a printed circuit board **70**. In the example embodiment of FIGURE 1, the printed circuit board **70** includes a metal board **72**, such as a copper or aluminum board, with an insulating coating **74** disposed on the metal board **72**. Printed traces are disposed on the insulating coating **74** and define a selected electrical circuit or circuits including electrical terminals, bonding bumps, or bonding pads **80**, **82**. The lead **46** of the lead frame element **40** is soldered to the printed circuitry electrical terminal **80**, while the lead **52** of the lead frame element **42** is soldered to the printed circuitry electrical terminal **82**. The printed traces also includes a thermal terminal **84** which optionally is not connected with the electrical circuitry. The bottom principal surface **50** of the chip carrier **14** is preferably soldered or otherwise bonded to the thermal terminal **84** to provide a substantially thermally conductive pathway therebetween, so that heat generated in the light emitting chip **12** can conduct through the substantially thermally conductive chip carrier **14** to the thermal terminal **84** and thence to the printed circuit board **70**. Optionally, the bottom principal surface **50** of the chip carrier **14** includes a metal layer for solder attach to the board or other coating to enhance thermal contact and heat transfer.

In one embodiment, the attachment bonding the leads **46**, **52** to the terminals **80**, **82** and the attachment bonding the bottom principal surface **50** of the chip carrier **14** to the thermal terminal **84** are the same. For example, these attachments can all be made by solder bonds in a single bonding process. Alternatively, a different type of attachment is used for bonding the bottom principal surface **50** of the chip carrier **14** to the thermal terminal **84** as compared with the type of attachment used for bonding the leads **46**, **52** to the terminals **80**, **82**. In this latter approach, the thermal attachment of the chip carrier **14** and the electrical attachments of the leads **46**, **52** can be separately optimized for thermal and electrical conductance, respectively.

FIGURES 2A and 2B show top and side views of a light emitting package **110**. The package **110** is similar to the package **10** of FIGURE 1. Elements of the light emitting package **110** that correspond with elements of the package **10** are labeled by reference numbers offset by 100. The package

110 includes a light emitting chip **112** flip chip bonded to conductive layers **120**, **122** disposed on a top principal surface **126** of a chip carrier **114**. A gap **128** electrically isolates the conductive layers **120**, **122**. Lead frame elements **140**, **142** are soldered or otherwise electrically contacted and mechanically bonded with the conductive layers **120**, **122** disposed on the top principal surface **126** of the chip carrier **114**. The lead frame elements **140**, **142** each include a bend **148**, **154** so that electrical leads **146**, **152** distal from the chip carrier **114** are approximately coplanar with a bottom principal surface **150** of the chip carrier **114**.

As in the package **10**, at least the top principal surface **126** of the chip carrier **114** is electrically insulating, while the chip carrier **114** can be either electrically insulating, or electrically conductive with an insulator layer providing the electrically insulating top principal surface **126**. The chip carrier **114** is also preferably substantially thermally conductive. The lead frame **140**, **142** is electrically conductive, and is suitably made of copper or another metal. The package **110** as illustrated does not include an encapsulant or phosphor; however, these components are optionally added. If an encapsulant is added, the bottom principal surface **150** of the chip carrier **114** and the leads **146**, **152** of the leads should extend outside of the encapsulant.

Advantageously, the light emitting package **110** does not include wire bonds. Rather, electrical connection between the lead frame **140**, **142** and the light emitting chip **112** is through the conductive layers **120**, **122**. As best seen in FIGURE 2A, the conductive layers **120**, **122** are large area layers, providing good conductance even if the thicknesses of the conductive layers **120**, **122** is limited. Moreover, the conductive layers **120**, **122** can be reflective layers that reflectively increase light extraction. The light emitting package **110** is suitable for surface mounting on a printed circuit board or other substrate. To perform surface mounting, the leads **146**, **152** are soldered or otherwise electrically bonded to bonding bumps, bonding pads, or other electrical terminals of printed circuitry, while the bottom principal surface **150** of the chip carrier **114** is preferably soldered or otherwise thermally bonded to the printed circuit board or other substrate.

With reference to FIGURE 3, a light emitting package **210** is described. The package **210** is similar to the package **10** of FIGURE 1. Elements of the light emitting package **210** that correspond with elements of the package **10** are labeled by reference numbers offset by 200. The package **210** includes a light emitting chip **212** bonded to a conductive layer **220** disposed on a top principal surface of a chip carrier **214**. Unlike the package **10**, however, in the package **210** the light emitting chip **212** is not flip-chip bonded. Rather, the light emitting chip **212** is bonded in a non-inverted configuration and includes an electrically conductive backside serving as an electrode that is electrically bonded to the conductive layer **220** using thermosonic bonding, conductive epoxy, solder, or the like. The front-side electrode of the light emitting chip **212** is wire bonded to another conductive layer **222** separated from the conductive layer **220** by a gap **228**. The wire bond **290** reaches across the gap **228** to electrically connect a front-side electrode **292** of the light emitting chip **212** with the conductive layer **222**.

Lead frame elements **240**, **242** are soldered or otherwise electrically contacted and mechanically bonded with the conductive layers **220**, **222** disposed on the top principal surface of the chip carrier **214**. Similarly to the corresponding lead frame elements of the packages **10**, **110**, the lead frame elements **240**, **242** each include a bend **248**, **254** so that electrical leads **246**, **252** are approximately coplanar with a bottom principal surface of the chip carrier **214**. Similarly to the package **10**, an encapsulant **260** encapsulates the light emitting chip **212**, the wire bond **290**, the top principal surface of the chip carrier **214**, and portions of the lead frame elements **240**, **242**, while the leads **246**, **252** and the bottom principal surface of the chip carrier **214** extend outside of the encapsulant **260**. Moreover, the light emitting package **210** includes a phosphor coating **262**.

While phosphor-coated encapsulants are shown in FIGURES 1 and 3, it is to be appreciated that encapsulation without a phosphor can be employed instead, or the phosphor can be dispersed in the encapsulant, or the phosphor can be otherwise arranged to interact with light produced by the light emitting chip. Moreover, it is contemplated to include a phosphor layer without an

encapsulant, or to include neither an encapsulant nor phosphor, as shown in FIGURE 2.

With reference to FIGURES 4A, 4B, and 4C, a light emitting package **310** is described. The package **310** is similar to the package **10** of FIGURE 1. Elements of the light emitting package **310** that correspond with elements of the package **10** are labeled by reference numbers offset by 300. The package **310** includes four light emitting chips **312A**, **312B**, **312C**, **312D** flip-chip bonded to conductive layers **320**, **322**, **324** disposed on a top principal surface of a chip carrier **314**. The conductive layers **320**, **322**, **324** are arranged with the layer **324** disposed between the layers **320**, **322** and acting as a series interconnect terminal. The conductive layers **320**, **324** are separated by a gap **328**, while the conductive layers **322**, **324** are separated by a gap **330**. The light emitting chips **312A**, **312B** are flip chip bonded across the gap **328** with electrodes bonding to the conductive layers **320**, **324**, while the light emitting chips **312C**, **312D** are flip chip bonded across the gap **330** with electrodes bonding to the conductive layers **322**, **324**. Thus, the light emitting chips **312A**, **312B** are connected electrically in parallel with each other, and similarly the light emitting chips **312C**, **312D** are connected electrically in parallel with each other. The parallel combination of chips **312A**, **312B** is connected electrically in series with the parallel combination of chips **312C**, **312D** via the series interconnect terminal conductive layer **324**.

Lead frame elements **340**, **342** are soldered or otherwise electrically contacted and mechanically bonded with the conductive layers **320**, **322** disposed on the top principal surface of the chip carrier **314**. Similarly to the corresponding lead frame elements of the packages **10**, **110**, the lead frame elements **340**, **342** each include a bend **348**, **354** so that electrical leads **346**, **352** are approximately coplanar with a bottom principal surface of the chip carrier **314**, so that the light emitting chip package **310** can be surface mounted by soldering or otherwise connecting the leads **346**, **352** of the lead frame elements **340**, **342** to a printed circuit board or other support. Preferably, the surface mounting also includes forming a solder bond or other thermal contact between the bottom principal surface of the chip carrier **314** and the printed

circuit board or other support. Although no encapsulant or phosphor is included in the light emitting package **310**, it will be appreciated that an encapsulant, phosphor, optical components, or the like are optionally included.

In another embodiment, the light emitting chips **312B**, **312D** are replaced by zener diodes connected across the gaps **328**, **330**, respectively. The zener diodes provide electrostatic discharge protection for the light emitting chips **312A**, **312C**. Moreover, it will be appreciated that other electronic components can be similarly added along with interconnecting circuitry defined by conductive areas on the top principal surface of the chip carrier **314**. Such other electronic components can regulate behavior of the light emitting chips, for example by providing input voltage conditioning, current limiting, or the like.

With reference to FIGURES 5A, 5B, and 5C, a light emitting package **410** is described. The package **410** is similar to the package **310** of FIGURES 4A, 4B, and 4C. Elements of the light emitting package **410** that correspond with elements of the package **310** are labeled by reference numbers offset by 100. The package **410** includes four light emitting chip **412A**, **412B**, **412C**, **412D** electrically connected with conductive layers **420**, **422**, **424** disposed on a top principal surface of a chip carrier **414**. The conductive layers **420**, **422**, **424** are arranged with the layer **424** disposed between the layers **420**, **422** and acting as a series interconnect terminal. The conductive layers **420**, **424** are separated by a gap **428**, while the conductive layers **422**, **424** are separated by a gap **430**. The light emitting chips **412A**, **412B** are arranged in a non-inverted orientation with an electrically conductive backside of each chip serving as an electrode bonded to the conductive layer **420**. Similarly, the light emitting chips **412C**, **412D** are arranged in a non-inverted orientation with an electrically conductive backside of each chip serving as an electrode bonded to the conductive layer **424**. A front-side electrode of the light emitting chip **412A** is wire bonded across the gap **428** to the conductive layer **424** by a wire bond **490A**. Similarly, a front-side electrode of the light emitting chip **412B** is wire bonded across the gap **428** to the conductive layer **424** by a wire bond **490B**. A front-side electrode of the light emitting chip **412C** is wire bonded across the

gap **430** to the conductive layer **422** by a wire bond **490C**. A front-side electrode of the light emitting chip **412D** is wire bonded across the gap **430** to the conductive layer **422** by a wire bond **490D**. Thus, the light emitting chips **412A**, **412B** are connected electrically in parallel with each other, and similarly
5 the light emitting chips **412C**, **412D** are connected electrically in parallel with each other. The parallel combination of chips **412A**, **412B** is connected electrically in series with the parallel combination of chips **412C**, **412D** via the series interconnect terminal conductive layer **424**.

Lead frame elements **440**, **442** are soldered or otherwise electrically
10 contacted and bonded with the conductive layers **420**, **422** disposed on the top principal surface of the chip carrier **414**. Similarly to the corresponding lead frame elements of the packages **10**, **110**, the lead frame elements **440**, **442** each include a bend **448**, **454** so that electrical leads **446**, **452** are approximately coplanar with a bottom principal surface of the chip carrier **414**,
15 so that the light emitting chip package **410** can be surface mounted by soldering or otherwise connecting the leads **446**, **452** to a printed circuit board or other support. Preferably, the surface mounting also includes forming a solder bond or other thermal contact between the bottom principal surface of the chip carrier **414** and the printed circuit board or other support. Although no
20 encapsulant or phosphor is included in the light emitting package **410**, it will be appreciated that an encapsulant, phosphor, optical components, or the like are optionally included.

In FIGURES 3 and 5 a single wire bond is used to electrically connect a frontside electrode of each chip, with the second electrode of each chip
25 corresponding to the electrically conductive backside of the chip. However, it is also contemplated to employ an insulating backside and two front side contacts that are each wire bonded to one of the conductive films disposed on the front principal surface of the chip carrier.

The light emitting packages described herein are suitably constructed
30 using electronic packaging processes. One example process is as follows. The process preferably starts with a chip carrier wafer which will be diced to produce a large number of light emitting packages each including a chip carrier

diced from the chip carrier wafer. If the chip carrier is electrically conductive, it is preferably coated, oxidized, or otherwise processed to form an electrically insulating layer at least on the top principal surface. Two or more patterned conductive layers are formed on the top principal surface of the chip carrier using metal evaporation, electroplating, or the like in conjunction with lithographic techniques that define the electrically isolating gaps between the conductive layers. These patterned conductive layers are the electrical terminal conductive layers, such as the layers 20, 22 of the package of FIGURE 1. Optionally, the bottom principal surface of the chip carrier is also metallized to allow for solder attach to improve thermal conductivity through the bottom principal surface. The light emitting chips are attached mechanically and electrically to the chip carriers by flip-chip bonding, wire bonding, or the like. The chip carrier wafer is then diced to produce a plurality of chip carriers with attached light emitting chips.

Each chip carrier produced by the dicing is processed in the example process as follows. The top principal surface of the chip carrier is soldered to the lead frame. Preferably, the two lead frame elements are secured together by tabs or other fasteners during this soldering, and in one embodiment a number of such lead frames are secured together in a linear or two-dimensional array to facilitate automated processing. A transfer molding process is used to form the encapsulant over the light emitting chips, the top principal surface of the chip carrier, and portions of the lead frame. The molding die is designed so that the leads and the bottom principal surface of the chip carrier extend outside the molded encapsulant. The tabs of the lead frames are then cut or trimmed to electrically separate the lead frame elements to produce the final light emitting package that is suitable for surface mounting by soldering or the like.

The invention has been described with reference to the preferred embodiments. Obviously, modifications and alterations will occur to others upon reading and understanding the preceding detailed description. It is intended that the invention be construed as including all such modifications